# **Inverter R&D**

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### **Overview**

### Timeline

- Start FY13
- Finish FY15
- 22% complete

### Budget

- Total project funding
  - DOE share 100%
- Funding for FY13: \$ 500K

### **Barriers**

- Availability and the cost of wide bandgap (WBG) devices will certainly be a barrier for achieving the cost target.
- Integrating the high temperature WBG module with the gate drive into the inverter.

### **Targets Addressed**

- DOE 2020 Power Electronics Targets
  - Power density: >13.4 kW/l
  - Specific power: >14.1 kW/kg
  - Efficiency: >94%

### **Partners**

- ORNL Curt Ayers, Steven Campbell, Cliff White, Randy Wiles, Burak Ozpineci, John Miller
- NREL (Jason Lustbader)
- WBG manufacturers
- Inverter component suppliers



## **Project Objective**

## Overall Objective

- Develop and design a WBG 55 kW inverter utilizing the WBG device attributes.
- Reduce size, weight, and cost of the inverter to meet the 2020 inverter targets.

# • FY13 Objective

 Design, build, and test a 10 kW WBG based prototype using commercially available WBG modules.



### **Milestones**

Date	Milestones and Go/No-Go Decisions	Status
August 2013	<u>Go/No-Go decision</u> : Perform design review of the 10 kW inverter to determine if design can meet the DOE 2020 Power Electronics Targets.	
September 2013	Milestone: Design, build, and test a 10 kW WBG based prototype using commercially available WBG modules.	On track.
September 2013	<u>Milestone:</u> Prepare a summary report that documents the results, findings, performance comparisons, and recommendations to be incorporated into the annual VTO report.	On track.



## **Approach/Strategy**

#### **Device Level Testing:**

- Maintain cognizance of state-of-the-art WBG power devices and acquire, test, and characterize newer technology WBG power devices.
- Develop loss models and circuit models using the test data and understand inverter benefits.

#### Module Level Testing:

• Develop and build a single phase test bed based on conventional mid-point converter architecture to evaluate WBG module performance.

#### **WBG Inverter Development:**

- Design a 10 kW inverter using <u>commercially available WBG devices/modules</u> to demonstrate the performance targets scaled to 30 kW operation.
- Enhance the 10 kW inverter design using <u>the high temperature packages and the gate</u> <u>drivers developed at ORNL</u> to show the feasibility of achieving 2020 targets.
- Scale the low power inverter design to demonstrate the performance at 30 kW continuous and 55 kW peak power operation while meeting the 2020 targets.



## **Approach/Strategy**

• The goal of this research is to reduce size and weight of the power converters to meet the 2020 inverter targets.

### Cost reduction can be achieved:

- reduce components by integrating functionality
- eliminate/reduce the existing liquid cooling loops
- decrease the manufacturing costs by reducing the part count and steps in manufacturing
- minimize high cost materials, like copper, through bus bar optimization current reduction



#### WBG device characterization and evaluation:

- Acquired device prototypes from WBG manufacturers
- ✓ 1200 V , 7 A SiC super junction transistor (SJT)
- ✓ 600 V, 5 A Gallium Nitride (GaN) field effect transistor (FET)
- ✓ 1200 V 20 A normally-on junction field effect transistor (JFET).
- Evaluated 600 V, 7 A SiC SJT
- Obtained the static characteristics of a 600 V, 7 A SiC SJT over a temperature range of 25°C to 200°C at Ig= 200 mA.
- Obtained the switching characteristics over a temperature range of 25°C to 200°C at 400 V dc up to 7 A.







1200 V, 20 A SiC JFET



600 V, 5 A GaN FET





- Completed evaluation of 2012 Nissan LEAF<sup>\*</sup> silicon (Si) power module.
- Tested the Si module over a temperature range of 25°C to 150°C, at 365 V and up to 200 A.
- Utilized the data in the LEAF<sup>x</sup> system simulation model by the APEEM team and in the future will also be to used compare with WBG devices.



Test setup for evaluating 2012 Nissan LEAF® Si module





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### Single Phase Test Bed for component evaluation

- Acquired the silicon-on-insulator (SOI) latest generation gate driver
- Completed the data acquisition system in lab view for the test bed
- Completed the gate driver board and the control board design using commercially available component.
- Completed the static characterization of ORNL high temperature SiC MOSFET package



- Completed the inverter design using commercial SiC 1200 V, 100 A MOSFET modules.
- Completed the gate driver and control board design for the inverter using commercial components.



Power density : 10 kW/3.88 L = 2.6 kW/L.

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 Completed the initial design of 10 kW WBG inverter with ORNL high temperature SiC 1200 V, 100 A module layout.



Power density : 10 kW/1.24 L = 8.1 kW/L ~ 3.11 times higher than the commercial module based design.



### Enhanced air cooled inverter design

- Redesigned the inverter developed in FY11 using the thermal simulation results from NREL.
- Reduced the size of the initial inverter design by 33% with of fin design optimization.
- Balance of plant analysis is currently being conducted to establish the feasibility of air-cooling at system level.
- For results on thermal analysis refer to NREL's presentation APE019 (Jason Lustbader)



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## **Collaboration and Coordination**

Organization	Type of Collaboration/Coordination	
NREL CONREL	Thermal analysis	
<ul> <li>WBG manufacturers:</li> <li>GeneSiC, CREE, USiC, General Electric,</li> <li>Infineon, HRL, International Rectifier</li> <li>CREE (CREE)</li> <li>Implementation (C</li></ul>	Device prototype supply	
Capacitor manufacturers: KEMET,SBE, AVX	Custom capacitor supply	



## **Proposed Future Work**

### Remainder of FY13

- Complete evaluation of the WBG device and develop loss models.
- Complete the single phase test bed and evaluation of the high temperature SiC module and SOI gate driver.
- Build and test the 10 kW commercial SiC module based inverter.

### • FY14

 Develop, design, and test a 10 kW prototype WBG inverter with high temperature module and high temperature gate driver.

## • FY15

 Develop, design, and test a 55 kW prototype WBG inverter with high temperature module and high temperature smart gate driver and integrate the novel protection and sense controls.





- **Relevance:** This project is targeted toward reducing volume, weight and cost of the traction drive inverter.
- WBG inverter development approach:
  - Design a 10 kW inverter using commercially available WBG devices/modules to demonstrate the performance targets scaled to 30 kW operation.
  - Design 10 kW inverter using the high temperature packages and the gate drivers developed at ORNL to show the feasibility of achieving 2020 targets.
  - Scale the low power inverter design to demonstrate the performance at 30 kW continuous and 55 kW peak power operation while meeting the 2020 targets.
- Collaborations: Collaborations with WBG device manufacturers, inverter component suppliers, and NREL are being used to maximize the impact of this work.

#### • Technical Accomplishments:

- Completed evaluation of 600 V, 7 A SiC SJT.
- Completed evaluation of 2012 Nissan LEAF Si power module.
- Completed data acquisition system in lab view and the gate driver board and the control board design with DSP interface for the single phase test bed.
- Completed the 10 kW inverter design using commercial SiC 1200 V, 100 A MOSFET modules.

